

60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	I _D Tc = +25°С
60V	$1.6m\Omega @ V_{GS} = 10V$	215A

Description and Applications

This new generation N-channel enhancement mode MOSFET is designed to minimize $R_{DS(ON)}$ yet maintain superior switching performance. This device is ideal for use in power management and load switch.

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

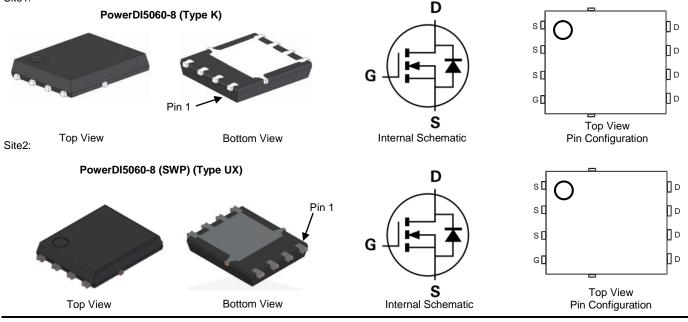
Site1:



- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High-Conversion Efficiency
- Low R_{DS(ON)} Minimizes on State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH61M8SPS-13	PowerDI5060-8 (Type K)	2,500 / Tape & Reel
DMTH61M8SPS-13	PowerDI5060-8 (SWP) (Type UX)	2,500 / Tape & Reel

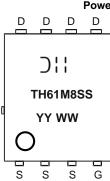
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



PowerDI5060-8 (Type K) / PowerDI5060-8 (SWP) (Type UX)

);;; = Manufacturer's Marking TH61M8SS = Product Type Marking Code YYWW or YYWW = Date Code Marking YY or YY = Year (ex: 20 = 2020) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	lo	215 150	А	
Maximum Continuous Body Diode Forward Current (Note	6)	ls	215	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	ldм	860	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	860	А
Avalanche Current, L = 1mH	las	35.8	А	
Avalanche Energy, L = 1mH		Eas	640.8	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	47	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



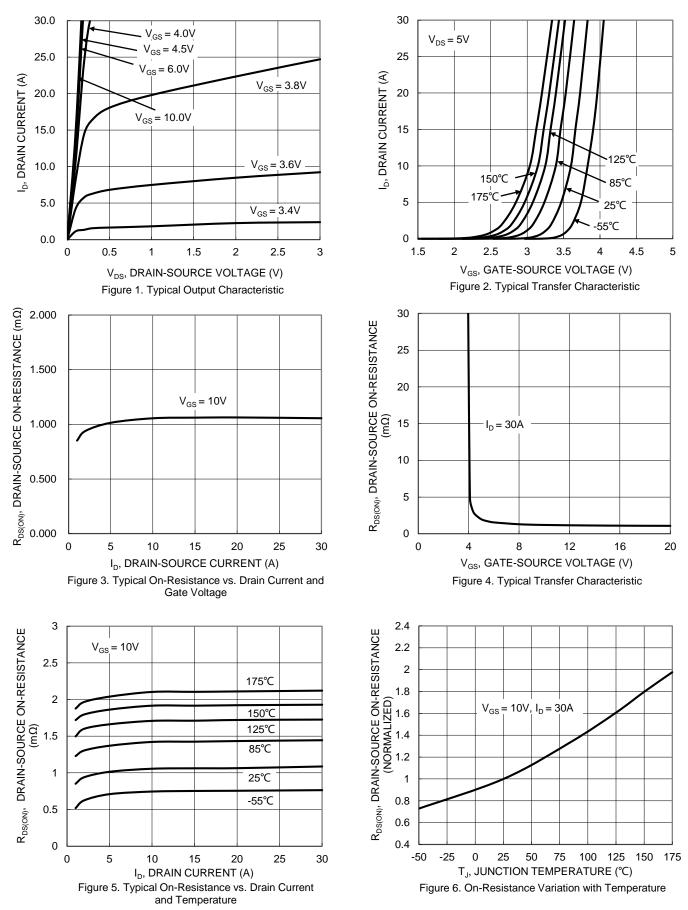
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Cymber		. , , ,	Шах	Unit	
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	2		4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	RDS(ON)		1.1	1.6	mΩ	V _{GS} = 10V, I _D = 30A
Diode Forward Voltage	Vsd		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	8306	—		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss		2735	-	pF	
Reverse Transfer Capacitance	Crss		184	—		
Gate Resistance	Rg	_	3.0	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	-	130.6	—		
Gate-Source Charge	Qgs	_	30.4	—	nC	V _{DS} = 30V, I _D = 30A, V _{GS} = 10V
Gate-Drain Charge	Q _{gd}	—	28.1	—		
Turn-On Delay Time	t _{D(ON)}	_	11.3	—		
Turn-On Rise Time	tR	—	28.5	—	ns	$\label{eq:VDD} \begin{array}{l} V_{DD}=30V, \ V_{GS}=10V, \\ I_D=30A, \ R_g=3\Omega \end{array}$
Turn-Off Delay Time	t _{D(OFF)}		86.2	—		
Turn-Off Fall Time	tF		47.6	—		
Body Diode Reverse Recovery Time	trr	_	70.4	—	ns	
Body Diode Reverse Recovery Charge	Qrr	—	127	—	nC	−I _F = 30A, di/dt = 100A/μs

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.



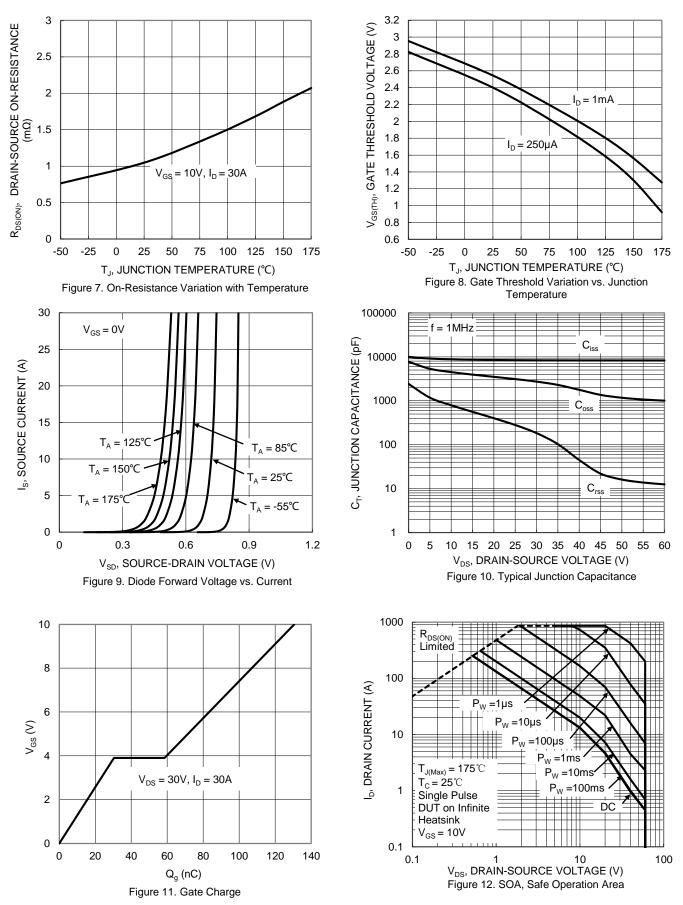
DMTH61M8SPS



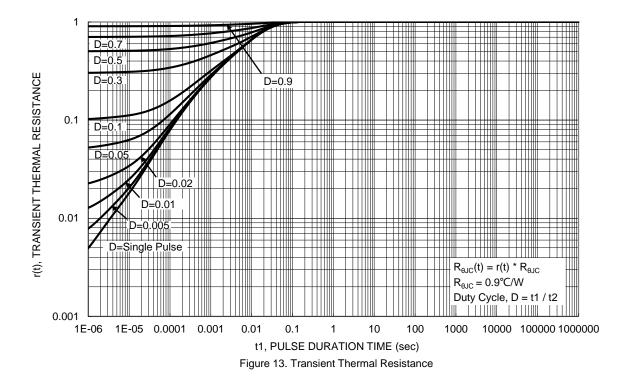
DMTH61M8SPS Document number: DS40997 Rev. 8 - 2



DMTH61M8SPS



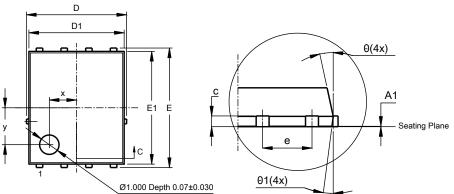


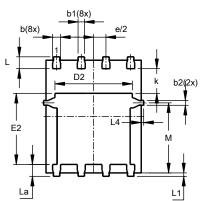




Package Outline Dimensions

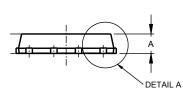
Please see http://www.diodes.com/package-outlines.html for the latest version. Site1: PowerDI5060-8 (Type K)





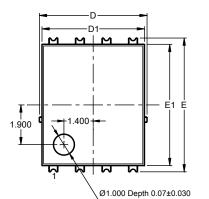


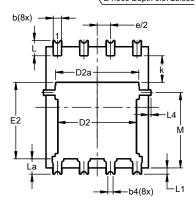
DETAIL A



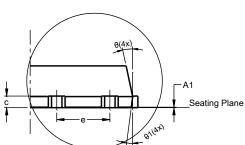
PowerDI5060-8					
	(Туре К)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
c D	0.23	0.33	0.277		
	5	.15 BS0	C		
D1	4.85	4.95	4.90		
D2	-	-	3.98		
E	6	6.15 BS0	C		
E1	5.75	5.85	5.80		
E2	3.56	3.725	3.66		
е	1	.27BSC)		
k	-	-	1.27		
L	0.51	0.71	0.61		
La	0.51	0.675	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
У	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All					

Site2:

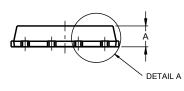




PowerDI5060-8 (SWP) (Type UX)



DETAIL A



PowerDI5060-8 (SWP) (Type UX)			
Dim	Min	Max	Тур
Α	0.90	1.10	1.00
A1	0	0.05	
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4	().25REF	-
С	0.230	0.330	0.277
D	5	.15 BS0	0
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
E	6	.40 BS0	0
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
е	1	.27BSC)
k	1.05		
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	0	.050RE	F
L4	0.025	0.225	0.125
М	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

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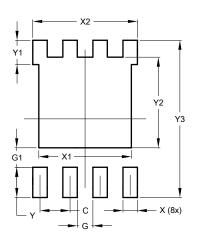


Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

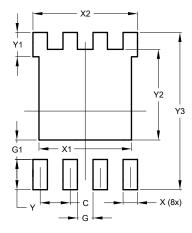
PowerDI5060-8 (Type K)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	3.910		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		

Site2:

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value
Dimensions	(in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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